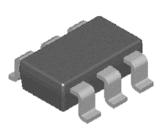
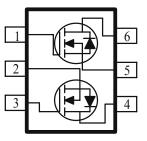
## N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSOP-6 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{\mathrm{DS(on)}} m(\Omega)$	I <sub>D</sub> (A)		
30	$63 @ V_{GS} = 4.5V$	3.5		
	$110 @ V_{GS} = 2.5V$	3.0		





ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Limit	Units			
Drain-Source Voltage			30	v		
Gate-Source Voltage			±12	v		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	J.	3.5	А		
Continuous Drain Current	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	ID	2.8			
Pulsed Drain Current <sup>b</sup>			16			
Continuous Source Current (Diode Conduction) <sup>a</sup>		Is	1.25	А		
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	P <sub>D</sub>	1.3	W		
Power Dissipation	$T_A=70^{\circ}C$	тD	0.8	**		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
	t <= 10 sec	Л	100	°C/W		
Maximum Junction-to-Ambient <sup>a</sup>	Steady-State	$R_{\theta JA}$	166	°C/W		

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)							
Democratica	C		Limits			TT . 4	
Parameter	Symbol	Test Conditions	Min	Min Typ Max		Unit	
Static							
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	0.7			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = 12 V$			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 24 V, V_{GS} = 0 V$ $V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			1 25	uA	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 4.5 V$	6			А	
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 3.5 \text{ A}$			63	mΩ	
	<sup>1</sup> DS(00)	$V_{GS} = 2.5 \text{ V}, I_D = 3 \text{ A}$			110	1112.2	
Forward Tranconductance <sup>A</sup>	$g_{\rm fs}$	$V_{DS} = 15 \text{ V}, I_D = 3.5 \text{ A}$		6.9		S	
Diode Forward Voltage	V <sub>SD</sub>	$I_{\rm S} = 2.3$ A, $V_{\rm GS} = 0$ V		0.8		V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_D = 3.5 \text{ A}$		6.3		nC	
Gate-Source Charge	Q <sub>gs</sub>			0.9			
Gate-Drain Charge	Q <sub>gd</sub>			1.9		]	
Input Capacitance	C <sub>iss</sub>			265			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz$		54		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			24			
Turn-On Delay Time	t <sub>d(on)</sub>			16			
Rise Time	t <sub>r</sub>	$V_{DD} = 25 \text{ V},  \text{R}_{\text{L}} = 25 \Omega ,  \text{I}\text{D} = 1 \text{ A},$		5		nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN} = 10 V$		23		115	
Fall-Time	t <sub>f</sub>			3			

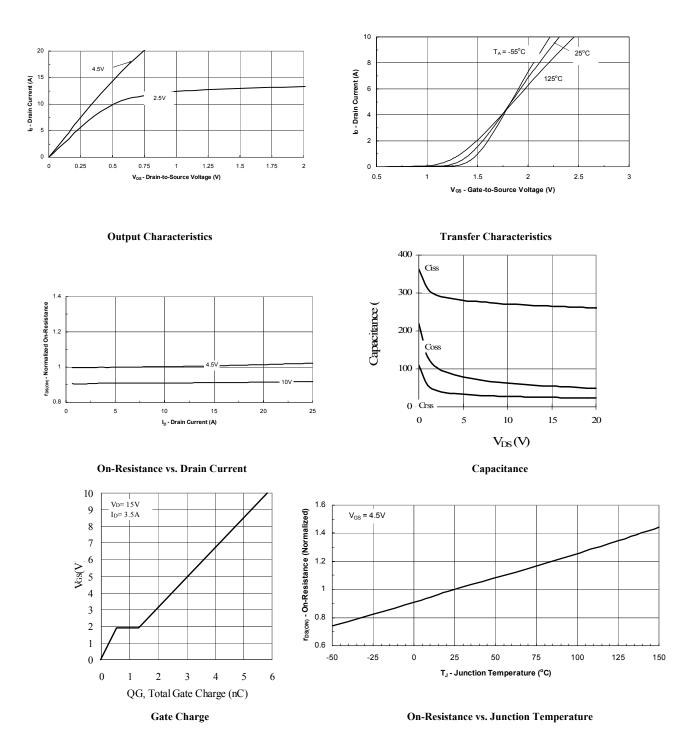
Notes

a. Pulse test:  $PW \le 300$  uty cycle  $\le 2\%$ .

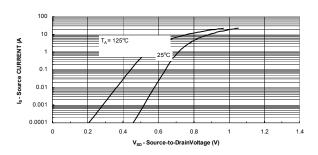
b. Guaranteed by design, not subject to production testing.

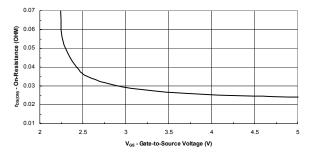
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Typical Electrical Characteristics (N-Channel)



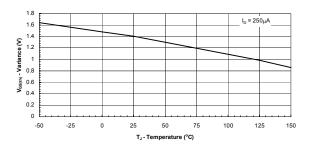
Typical Electrical Characteristics (N-Channel)

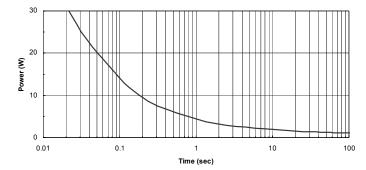


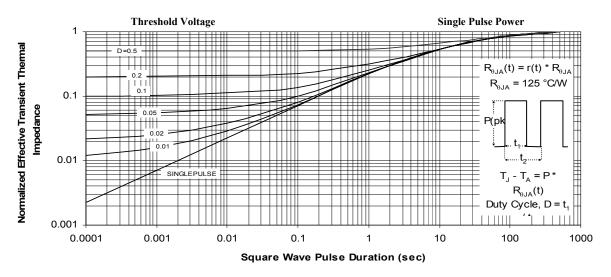


Source-Drain Diode Forward Voltage

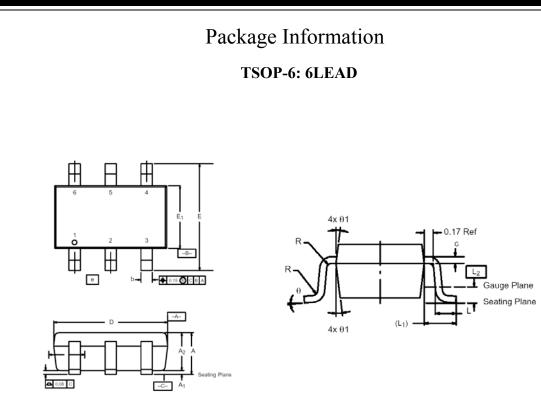
**On-Resistance vs.Gate-to Source Voltage** 







Normalized Thermal Transient Impedance, Junction-to-Ambient



	MILLIMETERS			INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A <sub>1</sub>	0.01	-	0.10	0.0004	-	0.004	
A <sub>2</sub>	0.84	-	1.00	0.033	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
E	2.70	2.85	2.98	0.106	0.112	0.117	
E <sub>1</sub>	1.55	1.65	1.70	0.061	0.065	0.067	
е	1.00 BSC			0.0394 BSC			
L	0.35	-	0.50	0.014	-	0.020	
L <sub>1</sub>	0.60 Ref			0.024 Ref			
L <sub>2</sub>	0.25 BSC			0.010 BSC			
R	0.10	-	-	0.004	-	_	
θ	0°	4°	8°	0°	4°	8°	
$\theta_1$	7° Nom			7° Nom			